

CLAIMS:

What is claimed is:

1 1. A photodetecting device comprising:
2 a first region of semiconductor material of a first conductivity type;
3 a second region of semiconductor material of a second conductivity
4 type opposite the first conductivity type and extending over a portion of the first
5 region, the device being configured to permit light to enter the second region;
6 third and fourth regions of semiconductor material of the first
7 conductivity type extending over portions of the second region, the third and
8 fourth regions being respectively coupled to first and second electrical contacts.

1 2. The device of claim 1 wherein the first conductivity type is P and
2 the second conductivity type is N.

1 3. The device of claim 1 wherein the third and fourth regions are
2 more heavily doped than the first region.

1 4. A method of using a photocell, comprising
2 exposing the photocell to incident light;
3 driving a sample node of the photocell to a reset value;
4 sensing a monitor node of the photocell, the signal values of the
5 monitor and sample nodes decaying in response to the incident light; and
6 driving the monitor node to a stop value in response to the signal
7 value of the monitor node having decayed to a predetermined value.

1 5. The method of claim 4 further comprising:
2 releasing the sample node after driving the sample node to the reset
3 value;
4 storing a first time value corresponding to the point in time of
5 releasing the sample node; and
6 storing a second time value corresponding to the point in time of
7 driving the monitor node.

1 6. The method of claim 4 wherein exposing is started after driving the
2 sample node.

1 7. The method of claim 4 further comprising:
2 reading an output value related to the signal value of the sample
3 node.

Sub a) 8. An imaging system comprising:
1 an image sensor having a plurality of photocells, the photocells
2 providing sensor signals in response to incident light and control signals, the
3 photocells being part of an integrated circuit (IC) die, the IC die having a first
4 region of semiconductor material of a first conductivity type, each of the plurality
5 of photocells having
6 a second region of semiconductor material of a second
7 conductivity type opposite the first conductivity type and extending over a
8 portion of the first region, the IC die being configured to permit the incident light
9 to enter the second region,

1 9. The imaging system of claim 8 wherein the plurality of photocells
2 define one or more sets of photocells, each set being associated with a respective
3 monitor node, the second contact of each photocell in a set being coupled to the
4 set's respective monitor node, the system being further configured to stop
5 integration in one or more of the sets in response to detecting a predetermined
6 value on the set's respective monitor node.

1 10. The imaging system of claim 8 wherein the plurality of photocells
2 define one set associated with a single monitor node.

Sub a 2 11. The imaging system of claim 8 wherein the plurality of photocells
Con 2 are arranged as an array and define a plurality of sets, each set defined by a
3 column of the array.

1 12. The imaging system of claim 8 further comprising
2 system controller for controlling the signal processing circuitry.

*a2
and 2*

13. The imaging system of claim 8 further comprising
optical system configured to receive the incident light to form an
3 image on the image sensor; and
4 communication interface for transferring the image data to an
5 image processing system separate from the imaging system.

1 14. The imaging system of claim 8 wherein the third and fourth regions
2 are formed as implants using a MOS fabrication process.

1 15. The imaging system of claim ~~8~~⁹ wherein each photocell further
2 comprises reset circuit configured to drive a voltage of the first contact to a reset
3 value in response to a first reset signal.

Sub a3 16. The imaging system of claim 9 wherein the control circuitry causes
1 the set's respective monitor node to be pulled high in response to detecting the
2 predetermined value.
ADD a4